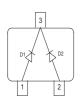


### Silicon Variable Capacitance Diodes

- For FM radio tuners with extended frequency band
- High tuning ratio at low supply voltage (car radio)
- Monolithic chip (common cathode) for perfect dual diode tracking
- Coded capacitance groups and group matching available
- Pb-free (RoHS compliant) package



#### BB814

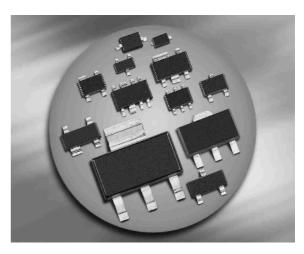


Туре	Package	Configuration	L <sub>S</sub> (nH)	Marking
BB814	SOT23	common cathode	1.8	SH1/2*

\*For differences see next page Capacitance groups

## **Maximum Ratings** at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V <sub>R</sub>	18	V
Peak reverse voltage-	V <sub>RM</sub>	20	
Forward current	I <sub>F</sub>	50	mA
Operating temperature range	T <sub>op</sub>	-55 125	°C
Storage temperature	T <sub>sta</sub>	-55 150	





Symbol		Values		
	min.	typ.	max.	1
·				
I <sub>R</sub>				nA
	-	-	20	
	-	-	200	
CT				pF
	43	44.75	46.5	
	19.1	20.8	22.7	
C <sub>T2</sub> /C <sub>T8</sub>	2.05	2.15	2.25	
$\Delta C_{T}/C_{T}$	-	-	3	%
r <sub>S</sub>	-	0.18	-	Ω
Q	-	200	-	
	$ \begin{array}{c} I_{R} \\ \hline \\  \\  \\  \\  \\  \\  \\  \\  \\  \\  \\  \\  \\  $	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c c c c c c c }\hline & & & & & & & & & & & & & & & & & & &$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

# **Electrical Characteristics** at $T_A = 25^{\circ}$ C, unless otherwise specified

 $^{1}$ Capacitance groups at 2V and 8V, coded 1; 2  $C_{T}/groups$  1 2

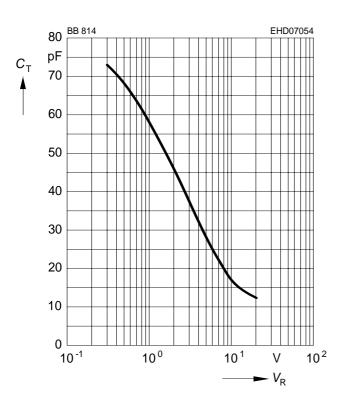
C <sub>2V</sub>	min	43pF	44.5pF
C <sub>2V</sub>	max	45pF	46.5pF
$C_{8V}$	min	19.1pF	19.75pF
C <sub>8V</sub>	max	21.95pF	22.7pF

<sup>2</sup>For details please refer to Application Note 047.



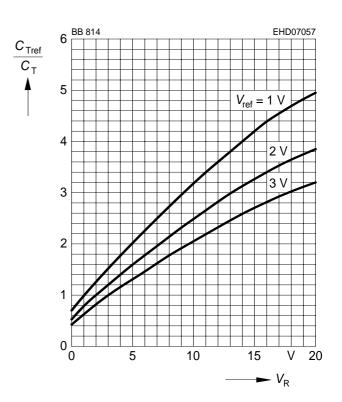
**Diode capacitance**  $C_{T} = f(V_{R})$ 

f = 1 MHz

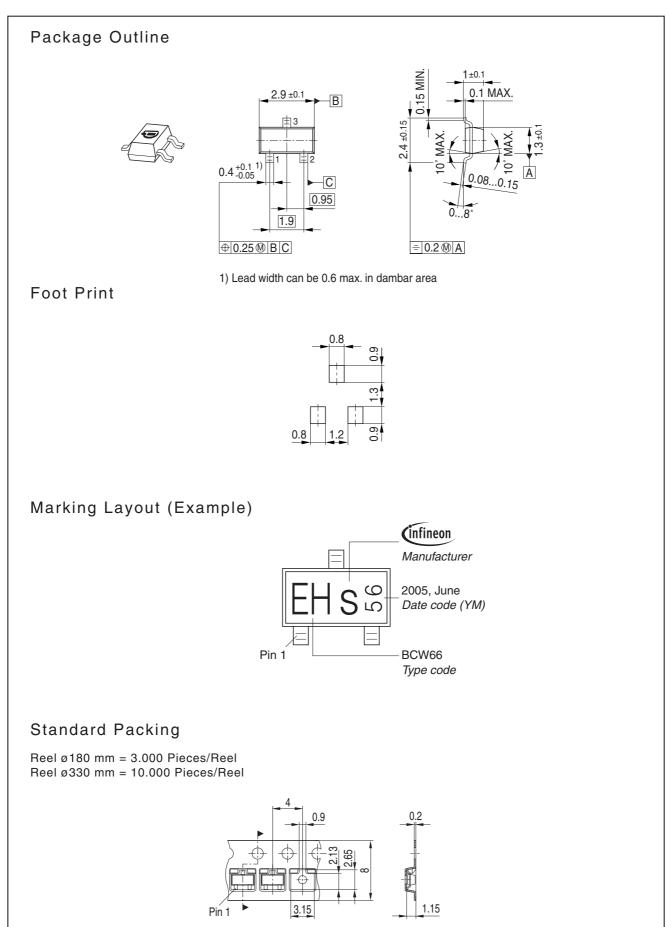


**Capacitance ratio**  $C_{\text{Tref}}/C_{\text{T}} = f(V_{\text{R}})$ 

f = 1 MHz









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